

### **Description**

The AU0571D1F is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power lines. The AU0571D1F complies with the IEC 61000-4-2 (ESD) with ± 30kV air and ± 30kV contact discharge. It is assembled into a SOD-123FL lead-free package. The small size and high ESD/surge protection make AU0571D1F an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

### **Features**

- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 5V
- Ultra low clamping voltage
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    Air discharge: ±30kV
    Contact discharge: ±30kV
  - IEC61000-4-5 (Lightning) 180A (8/20µs)
- RoHS Compliant

#### **Mechanical Characteristics**

- Package: SOD-123FL
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

#### **Applications**

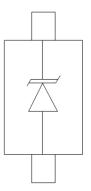
- Fast-charge battery chargers
- Power management system
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals

#### **Marking Information**



KE= Device Marking Code Bar denotes cathode

# **Pin Configuration**



Ordering Information

Part Number	Packaging	Reel Size
AU0571D1F	3000/Tape & Reel	7 inch



# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

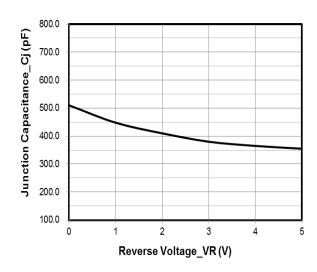
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	3600	W
Peak Pulse Current (8/20µs)	Ірр	180	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	±30 ±30	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

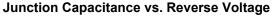
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6.4			V	IT = 1mA
Reverse Leakage Current	I <sub>R</sub>			1	μA	VRWM = 5V
Clamping Voltage	Vc			9	V	IPP = 5A (8 x 20µs pulse)
Clamping Voltage	Vc		20	25	V	IPP = 180A (8 x 20µs pulse)
Junction Capacitance	Сл			800	pF	VR = 0V, f = 1MHz

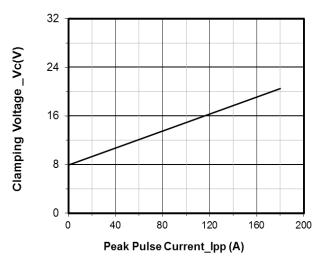


# AU0571D1F

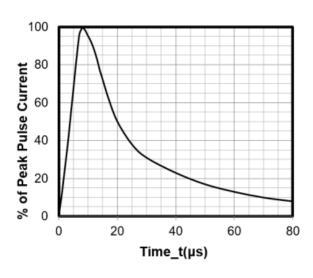


### Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)

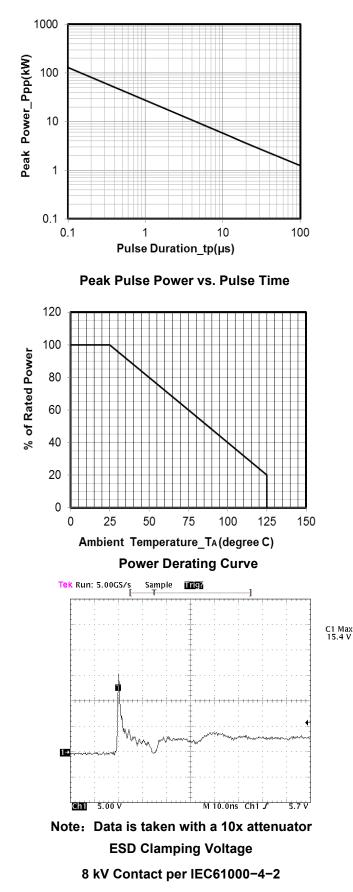




**Clamping Voltage vs. Peak Pulse Current** 

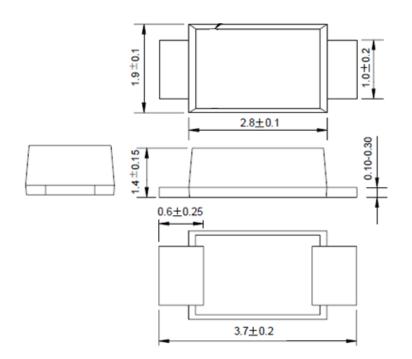


8 X 20µs Pulse Waveform





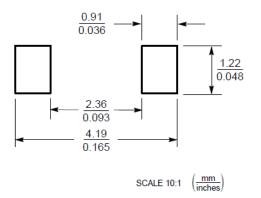
### SOD-123FL Package Outline Drawing



Dimen-

sions in millimeters

# **Suggested Land Pattern**



# **Contact Information**

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